

## Polar3™ HiPerFET™ **Power MOSFET**

# **IXFK80N60P3 IXFX80N60P3**

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode

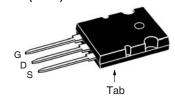


Symbol	Test Conditions	Maximum Ratings		
V <sub>DSS</sub>	$T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}$	600	V	
V <sub>DGR</sub>	$T_J = 25^{\circ}\text{C to } 150^{\circ}\text{C}, R_{GS} = 1M\Omega$	600		
V <sub>GSS</sub>	Continuous	± 30	V	
V <sub>GSM</sub>	Transient	± 40		
I <sub>D25</sub>	$T_{\rm c} = 25^{\circ}{\rm C}$	80	A	
	$T_{\rm c} = 25^{\circ}{\rm C}$ , Pulse Width Limited by $T_{\rm JM}$	200	A	
I <sub>A</sub>	$T_c = 25^{\circ}C$	40	A	
E <sub>AS</sub>	$T_c = 25^{\circ}C$	2	J	
$P_{D}$	T <sub>C</sub> = 25°C	1300	W	
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	35	V/ns	
T <sub>J</sub>		-55 +150	°C	
T <sub>JM</sub>		150	°C	
T <sub>stg</sub>		-55 +150	°C	
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C	
T <sub>SOLD</sub>	Plastic Body for 10s	260		
M <sub>d</sub>	Mounting Torque (TO-264)	1.13/10	Nm/lb.in	
F <sub>c</sub>	Mounting Force (PLUS247)	20120 /4.527	N/lb	
Weight	TO-264	10	g	
	PLUS247	6	g	

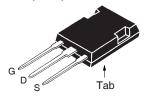
<b>Symbol</b> (T <sub>J</sub> = 25°C U	Test Conditions Inless Otherwise Specified)	Chara Min.	cteristic Typ.	Values Max	
BV <sub>DSS</sub>	$V_{GS} = 0V, I_D = 1mA$	600			V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 8mA$	3.0		5.0	V
I <sub>GSS</sub>	$V_{GS} = \pm 30V$ , $V_{DS} = 0V$			± 200	nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ , $V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			50 4	μA mA
R <sub>DS(on)</sub>	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$			77	mΩ

600V **80A** D25 =  $\mathbf{R}_{\mathrm{DS(on)}}$  $77m\Omega$ ≤ 250ns ≤

TO-264 (IXFK)



### PLUS247 (IXFX)



= Drain G = GateS = SourceTab = Drain

#### **Features**

- Dynamic dv/dt Rating
- Avalanche Rated
- Fast Intrinsic Diode
- Low Q<sub>G</sub>
- Low R<sub>DS(on)</sub>
   Low Drain-to-Tab Capacitance
- Low Package Inductance

#### **Advantages**

- Easy to Mount
- Space Savings

#### **Applications**

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode **Power Supplies**
- Uninterrupted Power Supplies
- AC Motor Drives
- High Speed Power Switching **Applications**

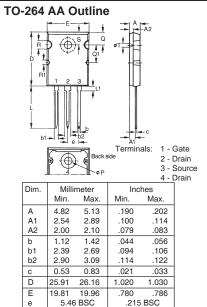


Symbol		Test Conditions nless Otherwise Specified)	Chara Min.	cteristic \	Values ∣ Max.
				Тур.	
g <sub>fs</sub>		$V_{DS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$	55	90	S
$\mathbf{C}_{iss}$	)			13.1	nF
$\mathbf{C}_{oss}$	}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		1240	pF
C <sub>rss</sub>	J			5.0	pF
$R_{gi}$		Gate Input Resistance		1.0	Ω
t <sub>d(on)</sub>	)	Resistive Switching Times		48	ns
t,		$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		25	ns
$\mathbf{t}_{d(off)}$		$R_{\rm G} = 10$ (External)		87	ns
t <sub>f</sub>	J	n <sub>G</sub> = 152 (External)		8	ns
$\mathbf{Q}_{g(on)}$	)			190	nC
$Q_{gs}$	}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		56	nC
$\mathbf{Q}_{gd}$	J			48	nC
R <sub>thJC</sub>					0.096 °C/W
R <sub>thCS</sub>				0.15	°C/W

#### Source-Drain Diode

Symb	ol Test Conditions	Characteristic Values			
$(T_J = 2)$	25°C, Unless Otherwise Specified)	Min.	Тур.	Max.	
Is	$V_{GS} = 0V$			80	Α
I <sub>SM</sub>	Repetitive, Pulse Width Limited by $T_{JM}$			320	Α
V <sub>SD</sub>	$I_F = I_S$ , $V_{GS} = 0V$ , Note 1			1.5	V
t <sub>rr</sub>	$I_{\rm F} = 40A$ , -di/dt = 100A/ $\mu$ s			250	ns
$\mathbf{Q}_{_{\mathrm{RM}}}$	<b>&gt;</b> '		1.4		μC
I <sub>RM</sub>	$V_{R} = 100V, V_{GS} = 0V$		13.0		Α

Note 1. Pulse test,  $t \le 300\mu s$ , duty cycle,  $d \le 2\%$ .



			1.07			_
	110	0.4		<b>^</b>	tline	
-	115	. /4			TIIN	2

0.00

0.00

20.32

2.29

3.17

6.07

8.38

3.81

1.78

6.04

0.25

0.25

20.83

2.59

3.66

6.27

8.69

4.32

2.29

6.30

.000

.000

.800

.090

.125

.239

.330

.150

.070

.238

.062

.010

.010

.820

.102

.144

.247

.342

.170

.090

.248

.072

J

K

L L1

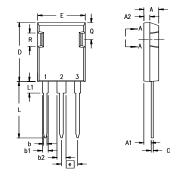
Р

Q

Q1

R R1

S

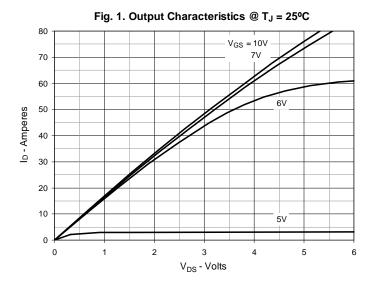


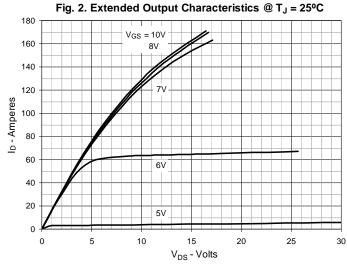
1 - Gate Terminals: 2 - Drain 3 - Source

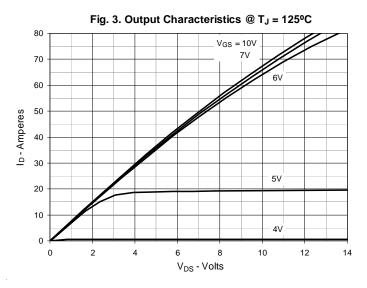
Dim.	Millimeter		Inc	hes
	Min.	Max.	Min.	Max.
Α	4.83	5.21	.190	.205
$A_1$	2.29	2.54	.090	.100
A <sub>2</sub>	1.91	2.16	.075	.085
b	1.14	1.40	.045	.055
b₁	1.91	2.13	.075	.084
b <sub>2</sub>	2.92	3.12	.115	.123
С	0.61	0.80	.024	.031
D	20.80	21.34	.819	.840
E	15.75	16.13	.620	.635
е	5.45 BSC		.215	BSC
L	19.81	20.32	.780	.800
L1	3.81	4.32	.150	.170
Q	5.59	6.20	.220	0.244
R	4.32	4.83	.170	.190

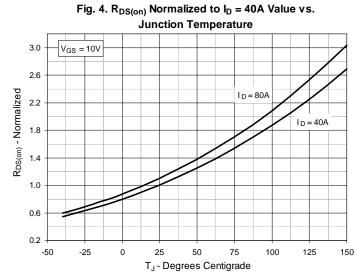
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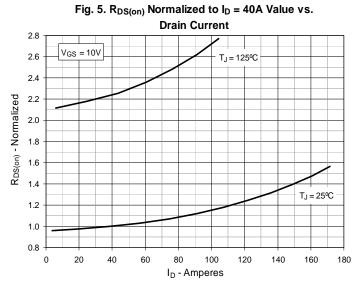


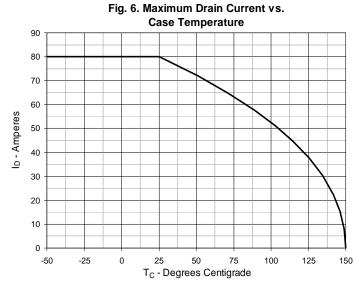




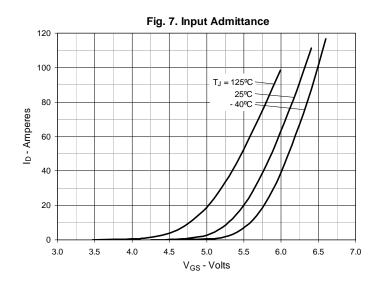


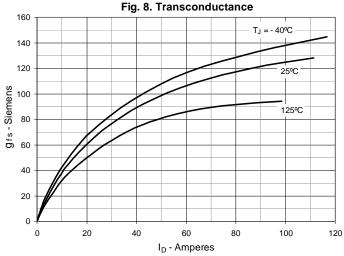


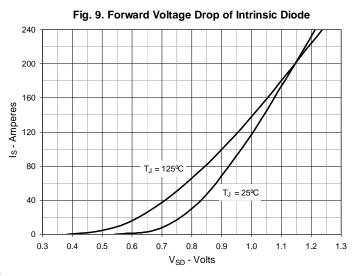


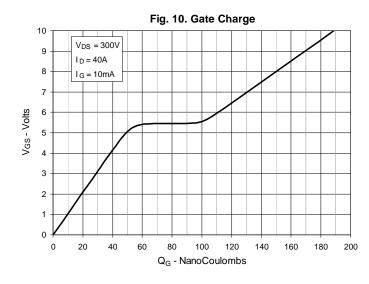


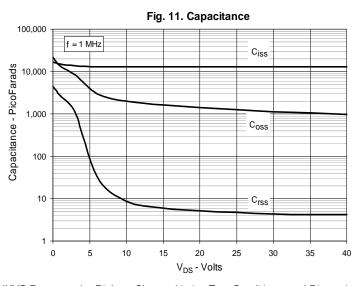


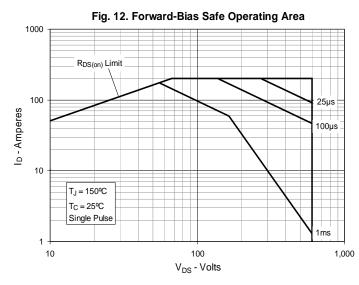




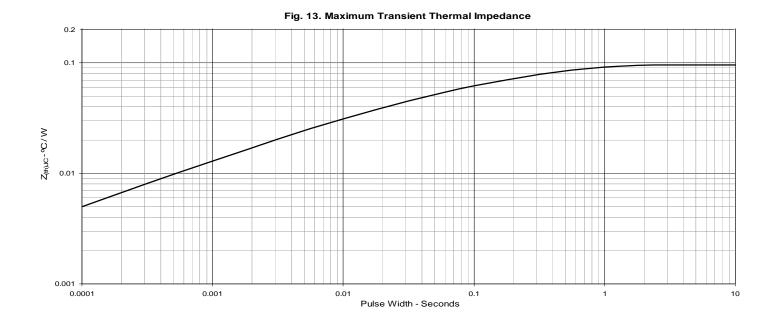








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